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Understanding Embedded - Microprocessors

Embedded microprocessors are specialized computing chips designed to perform specific tasks within an embedded system. Unlike general-purpose microprocessors found in personal computers, embedded microprocessors are tailored for dedicated functions within larger systems, offering optimized performance, efficiency, and reliability. These microprocessors are integral to the operation of countless electronic devices, providing the computational power necessary for controlling processes, handling data, and managing communications.

Applications of Embedded - Microprocessors

Embedded microprocessors are utilized across a broad spectrum of applications, making them indispensable in

Details	
Product Status	Obsolete
Core Processor	PowerPC e300
Number of Cores/Bus Width	1 Core, 32-Bit
Speed	266MHz
Co-Processors/DSP	Communications; QUICC Engine, Security; SEC
RAM Controllers	DDR, DDR2
Graphics Acceleration	No
Display & Interface Controllers	-
Ethernet	10/100/1000Mbps (1)
SATA	-
USB	USB 1.x (1)
Voltage - I/O	1.8V, 2.5V, 3.3V
Operating Temperature	-40°C ~ 105°C (TA)
Security Features	Cryptography, Random Number Generator
Package / Case	668-BBGA Exposed Pad
Supplier Device Package	668-PBGA-PGE (29x29)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/mpc8358ecvraddda

1 Overview

This section describes a high-level overview including features and general operation of the MPC8358E PowerQUICC II Pro processor. A major component of this device is the e300 core, which includes 32 Kbytes of instruction and data cache and is fully compatible with the Power Architecture™ 603e instruction set. The new QUICC Engine module provides termination, interworking, and switching between a wide range of protocols including ATM, Ethernet, HDLC, and POS. The QUICC Engine module's enhanced interworking eases the transition and reduces investment costs from ATM to IP based systems. The MPC8358E has a single DDR SDRAM memory controller. The MPC8358E also offers a 32-bit PCI controller, a flexible local bus, and a dedicated security engine.

Figure 1 shows the MPC8358E block diagram.

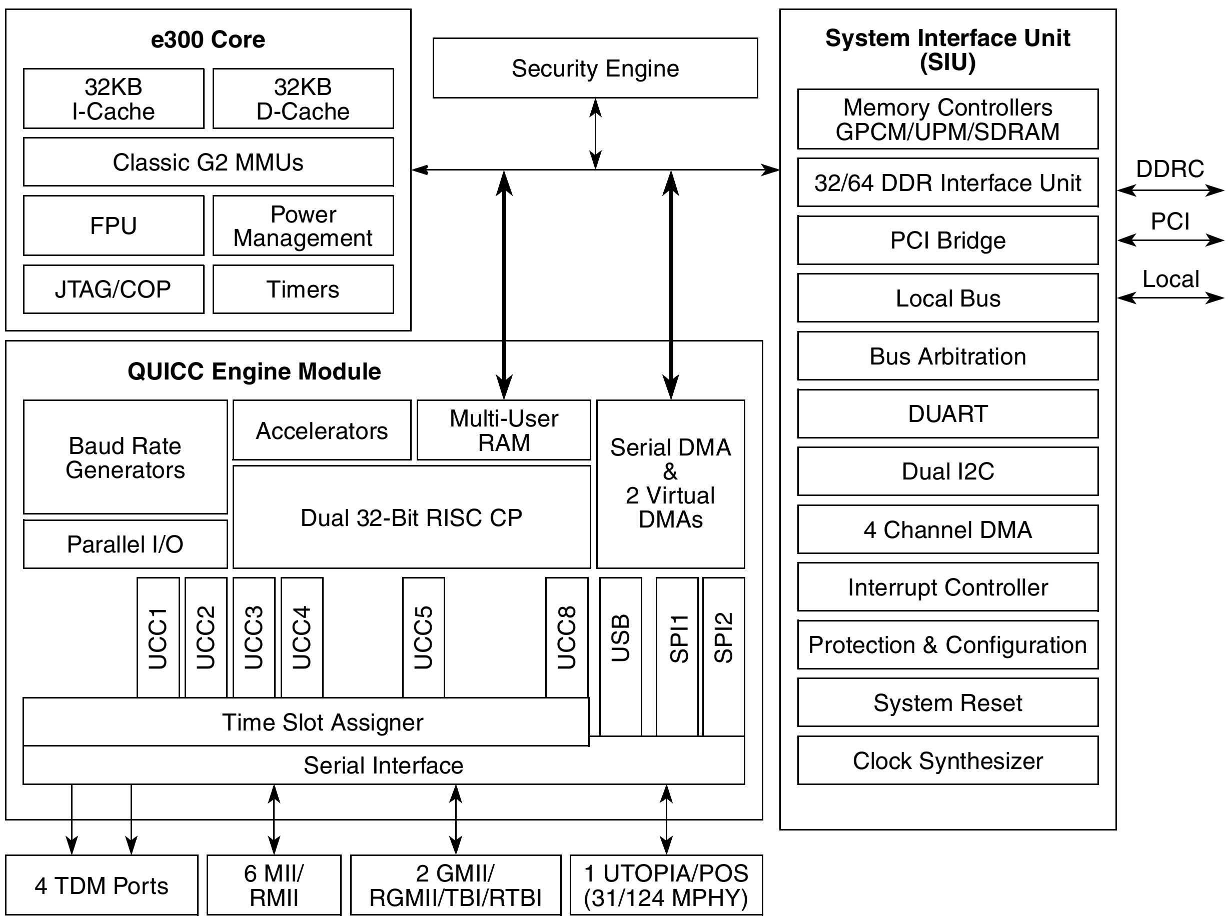

Figure 1. MPC8358E Block Diagram

Major features of the MPC8358E are as follows:

- e300 PowerPC processor core (enhanced version of the MPC603e core)
  - — Operates at up to 400 MHz (for the MPC8358E)
  - — High-performance, superscalar processor core
  - — Floating-point, integer, load/store, system register, and branch processing units

- — 32-Kbyte instruction cache, 32-Kbyte data cache
- — Lockable portion of L1 cache
- — Dynamic power management
- — Software-compatible with the Freescale processor families implementing the Power Architecture™ technology
- QUICC Engine unit
  - — Two 32-bit RISC controllers for flexible support of the communications peripherals, each operating up to 400 MHz (for the MPC8358E)
  - — Serial DMA channel for receive and transmit on all serial channels
  - — QUICC Engine module peripheral request interface (for SEC, PCI, IEEE Std. 1588™)
  - — Six UCCs on the MPC8358E supporting the following protocols and interfaces (not all of them simultaneously):
    - – IEEE 1588 protocol supported
    - – 10/100 Mbps Ethernet/IEEE Std. 802.3™ CDMA/CS interface through a media-independent interface (MII, RMII, RGMII)[1]
    - – 1000 Mbps Ethernet/IEEE 802.3 CDMA/CS interface through a media-independent interface (GMII, RGMII, TBI, RTBI) on UCC1 and UCC2
    - – 9.6-Kbyte jumbo frames
    - – ATM full-duplex SAR, up to 622 Mbps (OC-12/STM-4), AAL0, AAL1, and AAL5 in accordance ITU-T I.363.5
    - – ATM AAL2 CPS, SSSAR, and SSTED up to 155 Mbps (OC-3/STM-1) Mbps full duplex (with 4 CPS packets per cell) in accordance ITU-T I.366.1 and I.363.2
    - – ATM traffic shaping for CBR, VBR, UBR, and GFR traffic types compatible with ATM forum TM4.1 for up to 64-Kbyte simultaneous ATM channels
    - – ATM AAL1 structured and unstructured circuit emulation service (CES 2.0) in accordance with ITU-T I.163.1 and ATM Forum af-vtoa-00-0078.000
    - – IMA (Inverse Multiplexing over ATM) for up to 31 IMA links over 8 IMA groups in accordance with the ATM forum AF-PHY-0086.000 (Version 1.0) and AF-PHY-0086.001 (Version 1.1)
    - – ATM Transmission Convergence layer support in accordance with ITU-T I.432
    - – ATM OAM handling features compatible with ITU-T I.610
    - – PPP, Multi-Link (ML-PPP), Multi-Class (MC-PPP) and PPP mux in accordance with the following RFCs: 1661, 1662, 1990, 2686, and 3153
    - – IP support for IPv4 packets including TOS, TTL, and header checksum processing
    - – Ethernet over first mile IEEE 802.3ah
    - – Shim header
    - – Ethernet-to-Ethernet/AAL5/AAL2 inter-working
    - – L2 Ethernet switching using MAC address or IEEE Std. 802.1P/Q™ VLAN tags

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1.SMII or SGMII media-independent interface is not currently supported.

  - ATM (AAL2/AAL5) to Ethernet (IP) interworking in accordance with RFC2684 including bridging of ATM ports to Ethernet ports
  - Extensive support for ATM statistics and Ethernet RMON/MIB statistics
  - AAL2 protocol rate up to 4 CPS at OC-3/STM-1 rate
  - Packet over Sonet (POS) up to 622-Mbps full-duplex 124 MultiPHY
  - POS hardware; microcode must be loaded as an IRAM package
  - Transparent up to 70-Mbps full-duplex
  - HDLC up to 70-Mbps full-duplex
  - HDLC BUS up to 10 Mbps
  - Asynchronous HDLC
  - UART
  - BISYNC up to 2 Mbps
  - User-programmable Virtual FIFO size
  - QUICC multichannel controller (QMC) for 64 TDM channels
- One UTOPIA/POS interface on the MPC8358E supporting 31/124 MultiPHY
- Two serial peripheral interfaces (SPI); SPI2 is dedicated to Ethernet PHY management
- Four TDM interfaces on the MPC8358E with 1-bit mode for E3/T3 rates in clear channel
- Sixteen independent baud rate generators and 30 input clock pins for supplying clocks to UCC serial channels
- Four independent 16-bit timers that can be interconnected as four 32-bit timers
- Interworking functionality:
  - Layer 2 10/100-Base T Ethernet switch
  - ATM-to-ATM switching (AAL0, 2, 5)
  - Ethernet-to-ATM switching with L3/L4 support
  - PPP interworking

• Security engine is optimized to handle all the algorithms associated with IPSec, SSL/TLS, SRTP, 802.11i®, iSCSI, and IKE processing. The security engine contains four crypto-channels, a controller, and a set of crypto execution units (EUs).
  - Public key execution unit (PKEU) supporting the following:
    - RSA and Diffie-Hellman
    - Programmable field size up to 2048 bits
    - Elliptic curve cryptography
    - F2m and F(p) modes
    - Programmable field size up to 511 bits
  - Data encryption standard execution unit (DEU)
    - DES, 3DES
    - Two key (K1, K2) or three key (K1, K2, K3)
    - ECB and CBC modes for both DES and 3DES

- — Multiple master support
- — Master or slave I^2C mode support
- — On-chip digital filtering rejects spikes on the bus
- — System initialization data is optionally loaded from I^2C-1 EPROM by boot sequencer embedded hardware

- DMA controller
  - — Four independent virtual channels
  - — Concurrent execution across multiple channels with programmable bandwidth control
  - — All channels accessible by local core and remote PCI masters
  - — Misaligned transfer capability
  - — Data chaining and direct mode
  - — Interrupt on completed segment and chain
  - — DMA external handshake signals: $\overline{\text{DMA\_DREQ}}$[0:3]/$\overline{\text{DMA\_DACK}}$[0:3]/$\overline{\text{DMA\_DONE}}$[0:3]. There is one set for each DMA channel. The pins are multiplexed to the parallel IO pins with other QE functions.
- DUART
  - — Two 4-wire interfaces (RxD, TxD, RTS, CTS)
  - — Programming model compatible with the original 16450 UART and the PC16550D
- System timers
  - — Periodic interrupt timer
  - — Real-time clock
  - — Software watchdog timer
  - — Eight general-purpose timers
- IEEE Std. 1149.1™-compliant, JTAG boundary scan
- Integrated PCI bus and SDRAM clock generation

2 Electrical Characteristics

This section provides the AC and DC electrical specifications and thermal characteristics for the MPC8358E. The device is currently targeted to these specifications. Some of these specifications are independent of the I/O cell, but are included for a more complete reference. These are not purely I/O buffer design specifications.

4.1 DC Electrical Characteristics

Table 6 provides the clock input (CLKIN/PCI_SYNC_IN) DC timing specifications for the device.

Table 6. CLKIN DC Electrical Characteristics

Parameter	Condition	Symbol	Min	Max	Unit
Input high voltage	—	V_{IH}	2.7	OV_{DD} + 0.3	V
Input low voltage	—	V_{IL}	–0.3	0.4	V
CLKIN input current	$0\ V \le V_{IN} \le OV_{DD}$	I_{IN}	—	±10	μA
PCI_SYNC_IN input current	$0\ V \le V_{IN} \le 0.5V$ or $OV_{DD} - 0.5V \le V_{IN} \le OV_{DD}$	I_{IN}	—	±10	μA
PCI_SYNC_IN input current	$0.5\ V \le V_{IN} \le OV_{DD} - 0.5\ V$	I_{IN}	—	±100	μA

4.2 AC Electrical Characteristics

The primary clock source for the device can be one of two inputs, CLKIN or PCI_CLK, depending on whether the device is configured in PCI host or PCI agent mode. Table 7 provides the clock input (CLKIN/PCI_CLK) AC timing specifications for the device.

Table 7. CLKIN AC Timing Specifications

Parameter/Condition	Symbol	Min	Typical	Max	Unit	Notes
CLKIN/PCI_CLK frequency	f_{CLKIN}	—	—	66.67	MHz	1
CLKIN/PCI_CLK cycle time	t_{CLKIN}	15	—	—	ns	—
CLKIN/PCI_CLK rise and fall time	t_{KH}, t_{KL}	0.6	1.0	2.3	ns	2
CLKIN/PCI_CLK duty cycle	t_{KHK}/t_{CLKIN}	40	—	60	%	3
CLKIN/PCI_CLK jitter	—	—	—	±150	ps	4, 5

Notes:
1. **Caution:** The system, core, USB, security, and 10/100/1000 Ethernet must not exceed their respective maximum or minimum operating frequencies.
2. Rise and fall times for CLKIN/PCI_CLK are measured at 0.4 V and 2.7 V.
3. Timing is guaranteed by design and characterization.
4. This represents the total input jitter—short term and long term—and is guaranteed by design.
5. The CLKIN/PCI_CLK driver's closed loop jitter bandwidth should be <500 kHz at –20 dB. The bandwidth must be set low to allow cascade-connected PLL-based devices to track CLKIN drivers with the specified jitter.

4.3 Gigabit Reference Clock Input Timing

Table 8 provides the Gigabit reference clocks (GTX_CLK125) AC timing specifications.

Table 8. GTX_CLK125 AC Timing Specifications

At recommended operating conditions with LV_{DD} = 2.5 ± 0.125 mV/ 3.3 V ± 165 mV

Parameter/Condition	Symbol	Min	Typical	Max	Unit	Notes
GTX_CLK125 frequency	t_{G125}	—	125	—	MHz	—
GTX_CLK125 cycle time	t_{G125}	—	8	—	ns	—
GTX_CLK rise and fall time LV_{DD} = 2.5 V LV_{DD} = 3.3 V	t_{G125R}/t_{G125F}	—	—	 0.75 1.0	ns	1
GTX_CLK125 duty cycle GMII & TBI 1000Base-T for RGMII & RTBI	t_{G125H}/t_{G125}	 45 47	—	 55 53	%	2
GTX_CLK125 jitter	—	—	—	±150	ps	2

Notes:
1. Rise and fall times for GTX_CLK125 are measured from 0.5 and 2.0 V for LV_{DD} = 2.5 V and from 0.6 and 2.7 V for LV_{DD} = 3.3 V.
2. GTX_CLK125 is used to generate the GTX clock for the UCC Ethernet transmitter with 2% degradation. The GTX_CLK125 duty cycle can be loosened from 47%/53% as long as the PHY device can tolerate the duty cycle generated by GTX_CLK. See Section 8.2.2, "MII AC Timing Specifications," Section 8.2.3, "RMII AC Timing Specifications," and Section 8.2.5, "RGMII and RTBI AC Timing Specifications" for the duty cycle for 10Base-T and 100Base-T reference clock.

5 RESET Initialization

This section describes the DC and AC electrical specifications for the reset initialization timing and electrical requirements of the MPC8358E.

5.1 RESET DC Electrical Characteristics

Table 9 provides the DC electrical characteristics for the RESET pins of the device.

Table 9. RESET Pins DC Electrical Characteristics

Characteristic	Symbol	Condition	Min	Max	Unit
Input high voltage	V_{IH}	—	2.0	OV_{DD} + 0.3	V
Input low voltage	V_{IL}	—	–0.3	0.8	V
Input current	I_{IN}	—	—	±10	μA
Output high voltage	V_{OH}	I_{OH} = –8.0 mA	2.4	—	V
Output low voltage	V_{OL}	I_{OL} = 8.0 mA	—	0.5	V

Table 9. RESET Pins DC Electrical Characteristics (continued)

Characteristic	Symbol	Condition	Min	Max	Unit
Output low voltage	V_{OL}	I_{OL} = 3.2 mA	—	0.4	V

Notes:
1. This table applies for pins $\overline{\text{PORESET}}$, $\overline{\text{HRESET}}$, $\overline{\text{SRESET}}$, and $\overline{\text{QUIESCE}}$.
2. $\overline{\text{HRESET}}$ and $\overline{\text{SRESET}}$ are open drain pins, thus V_{OH} is not relevant for those pins.

5.2 RESET AC Electrical Characteristics

This section describes the AC electrical specifications for the reset initialization timing requirements of the device. Table 10 provides the reset initialization AC timing specifications for the DDR SDRAM component(s).

Table 10. RESET Initialization Timing Specifications

Parameter/Condition	Min	Max	Unit	Notes
Required assertion time of $\overline{\text{HRESET}}$ or $\overline{\text{SRESET}}$ (input) to activate reset flow	32	—	$t_{PCI\_SYNC\_IN}$	1
Required assertion time of $\overline{\text{PORESET}}$ with stable clock applied to CLKIN when the device is in PCI host mode	32	—	t_{CLKIN}	2
Required assertion time of $\overline{\text{PORESET}}$ with stable clock applied to PCI_SYNC_IN when the device is in PCI agent mode	32	—	$t_{PCI\_SYNC\_IN}$	1
$\overline{\text{HRESET}}$/$\overline{\text{SRESET}}$ assertion (output)	512	—	$t_{PCI\_SYNC\_IN}$	1
$\overline{\text{HRESET}}$ negation to $\overline{\text{SRESET}}$ negation (output)	16	—	$t_{PCI\_SYNC\_IN}$	1
Input setup time for POR config signals (CFG_RESET_SOURCE[0:2] and CFG_CLKIN_DIV) with respect to negation of $\overline{\text{PORESET}}$ when the device is in PCI host mode	4	—	t_{CLKIN}	2
Input setup time for POR config signals (CFG_RESET_SOURCE[0:2] and CFG_CLKIN_DIV) with respect to negation of $\overline{\text{PORESET}}$ when the device is in PCI agent mode	4	—	$t_{PCI\_SYNC\_IN}$	1
Input hold time for POR config signals with respect to negation of $\overline{\text{HRESET}}$	0	—	ns	
Time for the device to turn off POR config signals with respect to the assertion of $\overline{\text{HRESET}}$	—	4	ns	3
Time for the device to turn on POR config signals with respect to the negation of $\overline{\text{HRESET}}$	1	—	$t_{PCI\_SYNC\_IN}$	1, 3

Notes:
1. $t_{PCI\_SYNC\_IN}$ is the clock period of the input clock applied to PCI_SYNC_IN. When the device is In PCI host mode the primary clock is applied to the CLKIN input, and PCI_SYNC_IN period depends on the value of CFG_CLKIN_DIV. See the *MPC8360E PowerQUICC II Pro Integrated Communications Processor Family Reference Manual* for more details.
2. t_{CLKIN} is the clock period of the input clock applied to CLKIN. It is only valid when the device is in PCI host mode. See the *MPC8360E PowerQUICC II Pro Integrated Communications Processor Family Reference Manual* for more details.
3. POR config signals consists of CFG_RESET_SOURCE[0:2] and CFG_CLKIN_DIV.

Table 12. QUICC Engine Block Operating Frequency Limitations (continued)

Interface	Interface Operating Frequency (MHz)	Max Interface Bit Rate (Mbps)	Min QUICC Engine Operating Frequency[1] (MHz)	Notes
UART/async HDLC	3.68 (max internal ref clock)	115 (Kbps)	20	—
BISYNC	2 (max)	2	20	—
USB	48 (ref clock)	12	96	—

Notes:
1. The QUICC Engine module needs to run at a frequency higher than or equal to what is listed in this table.
2. ‘F’ is the actual interface operating frequency.
3. The bit rate limit is independent of the data bus width (that is, the same for serial, nibble, or octal interfaces).
4. TDM in high-speed mode for serial data interface.

6 DDR and DDR2 SDRAM

This section describes the DC and AC electrical specifications for the DDR and DDR2 SDRAM interface of the MPC8358E.

6.1 DDR and DDR2 SDRAM DC Electrical Characteristics

Table 13 provides the recommended operating conditions for the DDR2 SDRAM component(s) of the device when GV_{DD}(typ) = 1.8 V.

Table 13. DDR2 SDRAM DC Electrical Characteristics for GV_{DD}(typ) = 1.8 V

Parameter/Condition	Symbol	Min	Max	Unit	Notes
I/O supply voltage	GV_{DD}	1.71	1.89	V	1
I/O reference voltage	MV_{REF}	$0.49 \times GV_{DD}$	$0.51 \times GV_{DD}$	V	2
I/O termination voltage	V_{TT}	$MV_{REF} - 0.04$	$MV_{REF} + 0.04$	V	3
Input high voltage	V_{IH}	$MV_{REF} + 0.125$	$GV_{DD} + 0.3$	V	—
Input low voltage	V_{IL}	–0.3	$MV_{REF} - 0.125$	V	—
Output leakage current	I_{OZ}	—	±10	μA	4
Output high current (V_{OUT} = 1.420 V)	I_{OH}	–13.4	—	mA	—
Output low current (V_{OUT} = 0.280 V)	I_{OL}	13.4	—	mA	—
MV_{REF} input leakage current	I_{VREF}	—	±10	μA	—

Table 25. RGMII/RTBI DC Electrical Characteristics (when operating at 2.5 V)

Parameters	Symbol	Conditions		Min	Max	Unit
Supply voltage 2.5 V	LV_{DD}	—		2.37	2.63	V
Output high voltage	V_{OH}	I_{OH} = –1.0 mA	LV_{DD} = Min	2.00	LV_{DD} + 0.3	V
Output low voltage	V_{OL}	I_{OL} = 1.0 mA	LV_{DD} = Min	GND – 0.3	0.40	V
Input high voltage	V_{IH}	—	LV_{DD} = Min	1.7	LV_{DD} + 0.3	V
Input low voltage	V_{IL}	—	LV_{DD} = Min	–0.3	0.70	V
Input current	I_{IN}	$0 V \le V_{IN} \le LV_{DD}$		—	±10	μA

8.2 GMII, MII, RMII, TBI, RGMII, and RTBI AC Timing Specifications

The AC timing specifications for GMII, MII, TBI, RGMII, and RTBI are presented in this section.

8.2.1 GMII Timing Specifications

This sections describe the GMII transmit and receive AC timing specifications.

8.2.1.1 GMII Transmit AC Timing Specifications

Table 26 provides the GMII transmit AC timing specifications.

Table 26. GMII Transmit AC Timing Specifications

At recommended operating conditions with LV_{DD}/OV_{DD} of 3.3 V ± 10%.

Parameter/Condition	Symbol[1]	Min	Typ	Max	Unit	Notes
GTX_CLK clock period	t_{GTX}	—	8.0	—	ns	—
GTX_CLK duty cycle	$t_{GTXH/tGTX}$	40	—	60	%	—
GTX_CLK to GMII data TXD[7:0], TX_ER, TX_EN delay	t_{GTKHDX} t_{GTKHDV}	0.5 —	—	— 5.0	ns	—
GTX_CLK clock rise time, (20% to 80%)	t_{GTXR}	—	—	1.0	ns	—
GTX_CLK clock fall time, (80% to 20%)	t_{GTXF}	—	—	1.0	ns	—
GTX_CLK125 clock period	t_{G125}	—	8.0	—	ns	2
GTX_CLK125 reference clock duty cycle measured at $LV_{DD/2}$	t_{G125H}/t_{G125}	45	—	55	%	2

Notes:

1. The symbols used for timing specifications follow the pattern $t_{\text{(first two letters of functional block)(signal)(state)(reference)(state)}}$ for inputs and $t_{\text{(first two letters of functional block)(reference)(state)(signal)(state)}}$ for outputs. For example, t_{GTKHDV} symbolizes GMII transmit timing (GT) with respect to the t_{GTX} clock reference (K) going to the high state (H) relative to the time date input signals (D) reaching the valid state (V) to state or setup time. Also, t_{GTKHDX} symbolizes GMII transmit timing (GT) with respect to the t_{GTX} clock reference (K) going to the high state (H) relative to the time date input signals (D) going invalid (X) or hold time. Note that, in general, the clock reference symbol representation is based on three letters representing the clock of a particular functional. For example, the subscript of t_{GTX} represents the GMII(G) transmit (TX) clock. For rise and fall times, the latter convention is used with the appropriate letter: R (rise) or F (fall).
2. This symbol is used to represent the external GTX_CLK125 signal and does not follow the original symbol naming convention.

Figure 17 shows the TBI transmit AC timing diagram.

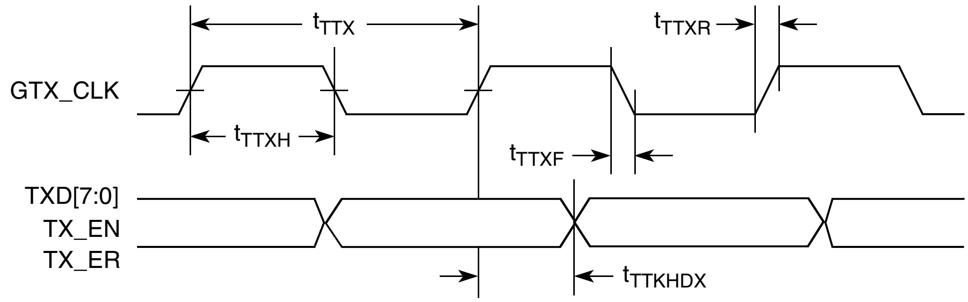

Figure 17. TBI Transmit AC Timing Diagram

8.2.4.2 TBI Receive AC Timing Specifications

Table 33 provides the TBI receive AC timing specifications.

Table 33. TBI Receive AC Timing Specifications

At recommended operating conditions with LV_{DD}/OV_{DD} of 3.3 V ± 10%.

Parameter/Condition	Symbol[1]	Min	Typ	Max	Unit	Notes
PMA_RX_CLK clock period	t_{TRX}	—	16.0	—	ns	—
PMA_RX_CLK skew	t_{SKTRX}	7.5	—	8.5	ns	—
RX_CLK duty cycle	t_{TRXH}/t_{TRX}	40	—	60	%	—
RCG[9:0] setup time to rising PMA_RX_CLK	t_{TRDVKH}	2.5	—	—	ns	2
RCG[9:0] hold time to rising PMA_RX_CLK	t_{TRDXKH}	1.0	—	—	ns	2
RX_CLK clock rise time, V_{IL}(min) to V_{IH}(max)	t_{TRXR}	0.7	—	2.4	ns	—
RX_CLK clock fall time, V_{IH}(max) to V_{IL}(min)	t_{TRXF}	0.7	—	2.4	ns	—

Notes:

1. The symbols used for timing specifications follow the pattern of $t_{\text{(first two letters of functional block)(signal)(state)(reference)(state)}}$ for inputs and $t_{\text{(first two letters of functional block)(reference)(state)(signal)(state)}}$ for outputs. For example, t_{TRDVKH} symbolizes TBI receive timing (TR) with respect to the time data input signals (D) reach the valid state (V) relative to the t_{TRX} clock reference (K) going to the high (H) state or setup time. Also, t_{TRDXKH} symbolizes TBI receive timing (TR) with respect to the time data input signals (D) went invalid (X) relative to the t_{TRX} clock reference (K) going to the high (H) state. Note that, in general, the clock reference symbol representation is based on three letters representing the clock of a particular functional. For example, the subscript of t_{TRX} represents the TBI (T) receive (RX) clock. For rise and fall times, the latter convention is used with the appropriate letter: R (rise) or F (fall). For symbols representing skews, the subscript is skew (SK) followed by the clock that is being skewed (TRX).
2. Setup and hold time of even numbered RCG are measured from riding edge of PMA_RX_CLK1. Setup and hold time of odd numbered RCG are measured from riding edge of PMA_RX_CLK0.

Table 39. Local Bus General Timing Parameters—DLL Enabled (continued)

Parameter	Symbol[1]	Min	Max	Unit	Notes
Local bus clock to LALE rise	t_{LBKHLR}	—	4.5	ns	—
Local bus clock to output valid (except LAD/LDP and LALE)	$t_{LBKHOV1}$	—	4.5	ns	—
Local bus clock to data valid for LAD/LDP	$t_{LBKHOV2}$	—	4.5	ns	3
Local bus clock to address valid for LAD	$t_{LBKHOV3}$	—	4.5	ns	3
Output hold from local bus clock (except LAD/LDP and LALE)	$t_{LBKHOX1}$	1.0	—	ns	3
Output hold from local bus clock for LAD/LDP	$t_{LBKHOX2}$	1.0	—	ns	3
Local bus clock to output high impedance for LAD/LDP	t_{LBKHOZ}	—	3.8	ns	—

Notes:
1. The symbols used for timing specifications follow the pattern of $t_{\text{(first two letters of functional block)(signal)(state)(reference)(state)}}$ for inputs and $t_{\text{(first two letters of functional block)(reference)(state)(signal)(state)}}$ for outputs. For example, $t_{LBIXKH1}$ symbolizes local bus timing (LB) for the input (I) to go invalid (X) with respect to the time the t_{LBK} clock reference (K) goes high (H), in this case for clock one (1). Also, t_{LBKHOX} symbolizes local bus timing (LB) for the t_{LBK} clock reference (K) to go high (H), with respect to the output (O) going invalid (X) or output hold time.
2. All timings are in reference to rising edge of LSYNC_IN.
3. All signals are measured from $OV_{DD}/2$ of the rising edge of LSYNC_IN to $0.4 \times OV_{DD}$ of the signal in question for 3.3-V signaling levels.
4. Input timings are measured at the pin.
5. $t_{LBOTOT1}$ should be used when RCWH[LALE] is not set and when the load on LALE output pin is at least 10 pF less than the load on LAD output pins.
6. $t_{LBOTOT2}$ should be used when RCWH[LALE] is set and when the load on LALE output pin is at least 10 pF less than the load on LAD output pins.
7. $t_{LBOTOT3}$ should be used when RCWH[LALE] is set and when the load on LALE output pin equals to the load on LAD output pins.
8. For purposes of active/float timing measurements, the Hi-Z or off-state is defined to be when the total current delivered through the component pin is less than or equal to the leakage current specification.

Table 40 describes the general timing parameters of the local bus interface of the device.

Table 40. Local Bus General Timing Parameters—DLL Bypass Mode

Parameter	Symbol[1]	Min	Max	Unit	Notes
Local bus cycle time	t_{LBK}	15	—	ns	2
Input setup to local bus clock	t_{LBIVKH}	7	—	ns	3, 4
Input hold from local bus clock	t_{LBIXKH}	1.0	—	ns	3, 4
LALE output fall to LAD output transition (LATCH hold time)	$t_{LBOTOT1}$	1.5	—	ns	5
LALE output fall to LAD output transition (LATCH hold time)	$t_{LBOTOT2}$	3	—	ns	6
LALE output fall to LAD output transition (LATCH hold time)	$t_{LBOTOT3}$	2.5	—	ns	7
Local bus clock to output valid	t_{LBKHOV}	—	3	ns	3

11 I^2C

This section describes the DC and AC electrical characteristics for the I^2C interface of the MPC8358E.

11.1 I^2C DC Electrical Characteristics

Table 43 provides the DC electrical characteristics for the I^2C interface of the device.

Table 43. I^2C DC Electrical Characteristics

At recommended operating conditions with OV_{DD} of 3.3 V ± 10%.

Parameter	Symbol	Min	Max	Unit	Notes
Input high voltage level	V_{IH}	$0.7 \times OV_{DD}$	$OV_{DD} + 0.3$	V	—
Input low voltage level	V_{IL}	–0.3	$0.3 \times OV_{DD}$	V	—
Low level output voltage	V_{OL}	0	0.4	V	1
Output fall time from V_{IH}(min) to V_{IL}(max) with a bus capacitance from 10 to 400 pF	t_{I2KLKV}	$20 + 0.1 \times C_B$	250	ns	2
Pulse width of spikes which must be suppressed by the input filter	t_{I2KHKL}	0	50	ns	3
Capacitance for each I/O pin	C_I	—	10	pF	—
Input current ($0\ V \le V_{IN} \le OV_{DD}$)	I_{IN}	—	±10	μA	4

Notes:
1. Output voltage (open drain or open collector) condition = 3 mA sink current.
2. C_B = capacitance of one bus line in pF.
3. Refer to the *MPC8360E Integrated Communications Processor Family Reference Manual* for information on the digital filter used.
4. I/O pins will obstruct the SDA and SCL lines if OV_{DD} is switched off.

11.2 I^2C AC Electrical Specifications

Table 44 provides the AC timing parameters for the I^2C interface of the device.

Table 44. I^2C AC Electrical Specifications

All values refer to V_{IH} (min) and V_{IL} (max) levels (see Table 43).

Parameter	Symbol[1]	Min	Max	Unit
SCL clock frequency	f_{I2C}	0	400	kHz
Low period of the SCL clock	t_{I2CL}	1.3	—	μs
High period of the SCL clock	t_{I2CH}	0.6	—	μs
Setup time for a repeated START condition	t_{I2SVKH}	0.6	—	μs
Hold time (repeated) START condition (after this period, the first clock pulse is generated)	t_{I2SXKL}	0.6	—	μs
Data setup time	t_{I2DVKH}	100	—	ns

16.1 SPI DC Electrical Characteristics

Table 54 provides the DC electrical characteristics for the device SPI.

Table 54. SPI DC Electrical Characteristics

Characteristic	Symbol	Condition	Min	Max	Unit
Output high voltage	V_{OH}	$I_{OH} = -6.0$ mA	2.4	—	V
Output low voltage	V_{OL}	$I_{OL} = 6.0$ mA	—	0.5	V
Output low voltage	V_{OL}	$I_{OL} = 3.2$ mA	—	0.4	V
Input high voltage	V_{IH}	—	2.0	$OV_{DD} + 0.3$	V
Input low voltage	V_{IL}	—	–0.3	0.8	V
Input current	I_{IN}	$0\text{ V} \le V_{IN} \le OV_{DD}$	—	±10	μA

16.2 SPI AC Timing Specifications

Table 55 and provide the SPI input and output AC timing specifications.

Table 55. SPI AC Timing Specifications[1]

Characteristic	Symbol[2]	Min	Max	Unit
SPI outputs—Master mode (internal clock) delay	t_{NIKHOX} t_{NIKHOV}	0.4 —	— 8	ns
SPI outputs—Slave mode (external clock) delay	t_{NEKHOX} t_{NEKHOV}	2 —	— 8	ns
SPI inputs—Master mode (internal clock) input setup time	t_{NIIVKH}	8	—	ns
SPI inputs—Master mode (internal clock) input hold time	t_{NIIXKH}	0	—	ns
SPI inputs—Slave mode (external clock) input setup time	t_{NEIVKH}	4	—	ns
SPI inputs—Slave mode (external clock) input hold time	t_{NEIXKH}	2	—	ns

Notes:

1. Output specifications are measured from the 50% level of the rising edge of CLKIN to the 50% level of the signal. Timings are measured at the pin.
2. The symbols used for timing specifications follow the pattern of $t_{\text{(first two letters of functional block)(signal)(state)(reference)(state)}}$ for inputs and $t_{\text{(first two letters of functional block)(reference)(state)(signal)(state)}}$ for outputs. For example, t_{NIKHOV} symbolizes the NMSI outputs internal timing (NI) for the time t_{SPI} memory clock reference (K) goes from the high state (H) until outputs (O) are valid (V).

Figure 40 provides the AC test load for the SPI.

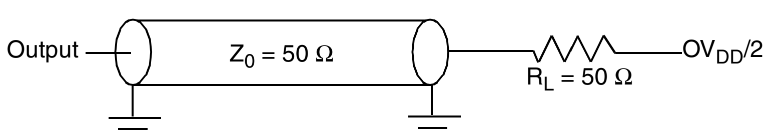

Figure 40. SPI AC Test Load

21 Package and Pin Listings

This section details package parameters, pin assignments, and dimensions. The MPC8358E is available in a plastic ball grid array (PBGA), see Section 21.1, "Package Parameters for the PBGA Package," and Section 21.2, "Mechanical Dimensions of the PBGA Package," for information on the package.

21.1 Package Parameters for the PBGA Package

The package parameters for rev 2.0 silicon are as provided in the following list. The package type is **29** mm x 29 mm, 668 plastic ball grid array (PBGA).

Package outline	**29 mm x 29 mm**
Interconnects	**668**
Pitch	**1.00 mm**
Module height (typical)	1.46 mm
Solder Balls	62 Sn/36 Pb/2 Ag *(*ZQ package)
	95.5 Sn/0.5 Cu/4Ag (VR package)
Ball diameter (typical)	0.64 mm

4. Datum A, the seating plane, is determined by the spherical crowns of the solder balls.
5. Parallelism measurement must exclude any effect of mark on top surface of package.
6. Distance from the seating plane to the encapsulant material.

21.3 Pinout Listings

Refer to AN3097, “MPC8360/MPC8358E PowerQUICC Design Checklist,” for proper pin termination and usage.

Table 65 shows the pin list of the MPC8358E PBGA package.

Table 65. MPC8358E PBGA Pinout Listing

Signal	Package Pin Number	Pin Type	Power Supply	Notes
DDR SDRAM Memory Controller Interface				
MEMC_MDQ[0:63]	AD20, AG24, AF24, AH24, AF23, AE22, AH26, AD21, AH25, AD22, AF27, AB24, AG25, AC22, AE25, AC24, AD25, AB25, AC25, AG28, AD26, AE23, AG26, AC26, AD27, V25, AA28, AA25, Y26, W27, U24, W24, E28, H24, E26, D25, G27, H25, G26, F26, F27, F25, D26, F24, G25, E27, D27, C28, C27, F22, B26, F21, B28, E22, D24, C24, A25, E20, F20, D20, A23, C21, C23, E19	I/O	GV_{DD}	—
MEMC_MECC[0:7]	N26, N24, J26, H28, N28, P24, L26, K24	I/O	GV_{DD}	—
MEMC_MDM[0:8]	AG23, AD23, AE26, V28, G28, D28, D23, B24, U27	O	GV_{DD}	—
MEMC_MDQS[0:8]	AH23, AH27, AF28, T28, H26, E25, B25, A24, R28	I/O	GV_{DD}	—
MEMC_MBA[0:2]	V26, W28, Y28	O	GV_{DD}	—
MEMC_MA[0:14]	L25, M25, M24, K28, P28, T24, M27, R25, P25, L28, U26, M28, L27, K27, H27	O	GV_{DD}	—
MEMC_MODT[0:3]	AE21, AC19, E23, B23	—	GV_{DD}	6
$\overline{\text{MEMC\_MWE}}$	R27	O	GV_{DD}	—
$\overline{\text{MEMC\_MRAS}}$	W25	O	GV_{DD}	—
$\overline{\text{MEMC\_MCAS}}$	R24	O	GV_{DD}	—
$\overline{\text{MEMC\_MCS}}$[0:3]	T26, U28, J25, F28	O	GV_{DD}	—
MEMC_MCKE[0:1]	AD24, AE28	O	GV_{DD}	—
MEMC_MCK[0:5]	AG22, AG27, A26, C26, P26, E21	O	GV_{DD}	—
$\overline{\text{MEMC\_MCK}}$[0:5]	AF22, AF26, A27, B27, N27, D22	O	GV_{DD}	—
MDIC[0:1]	F19, AA27	I/O	GV_{DD}	11
PCI				
$\overline{\text{PCI\_INTA}}$/ PF[5]	R3	I/O	$LV_{DD}2$	2
$\overline{\text{PCI\_RESET\_OUT}}$/ PF[6]	P6	I/O	$LV_{DD}2$	—
PCI_AD[0:31]/ PG[0:31]	AB5, AC5, AG1, AA5, AF2, AD4, Y6, AF1, AE2, AC4, AD3, AE1, Y4, AC3, AD2, AD1, AB2, Y3, AA1, Y1, W1, V6, W3, V4, T5, W2, V5, V1, U4, V2, U2, T2	I/O	$LV_{DD}2$	—
$\overline{\text{PCI\_C\_BE}}$[0:3]/ PF[7:10]	Y5, AC2, Y2, U5	I/O	OV_{DD}	—

Table 65. MPC8358E PBGA Pinout Listing (continued)

Signal	Package Pin Number	Pin Type	Power Supply	Notes
GV_{DD}	C19, C22, C25, G24, J18, J19, J20, J24, K19, K20, K26, L20, M20, M26, N19, N20, P20, P27, R20, T19, T20, T27, U19, U20, U25, V19, V20, W20, W26, Y20, AA24, AB28, AC21, AC28, AD28, AF21, AF25	Power for DDR DRAM I/O Voltage (2.5 V or 1.8 V)	GV_{DD}	—
$LV_{DD}0$	F3, J9	—	$LV_{DD}0$	—
$LV_{DD}1$	P3, P10	—	$LV_{DD}1$	10
$LV_{DD}2$	R4, R10	—	$LV_{DD}2$	10
V_{DD}	M12, M13, M16, M17, N10, N12, N13, N14, N15, N16, N17, P12, P13, P14, P15, P16, P17, R12, R13, R16, R17, T12, T13, T16, T17, U12, U13, U14, U15, U16, U17, V12, V13, V16, V17, W11, W12, W13, W15, W16, W17, Y16, Y17	Power for Core (1.2 V)	V_{DD}	—
OV_{DD}	C6, C12, D17, J11, J13, J14, K3, K9, K10, K12, K15, K16, L10, M9, N9, T9, U9, V3, V10, W9, W10, W14, Y9, Y10, Y12, Y13, Y15, AA3, AE6, AE16, AF11, AF20	PCI, 10/100 Ethernet, and other Standard (3.3 V)	OV_{DD}	—
MVREF1	J27	I	DDR Referenc e Voltage	—
MVREF2	Y24	I	DDR Referenc e Voltage	—
No Connect				
NC	F23, G23, H23, J23, K23, L23, M23, N23, P23, R23, T23, U23, V23, W23, Y23, AA23, AB23, AC23	—	—	—

Notes:
1. This pin is an open drain signal. A weak pull-up resistor (1 kΩ) should be placed on this pin to OV_{DD}.
2. This pin is an open drain signal. A weak pull-up resistor (2–10 kΩ) should be placed on this pin to OV_{DD}.
3. This output is actively driven during reset rather than being three-stated during reset.
4. These JTAG pins have weak internal pull-up P-FETs that are always enabled.
5. This pin should have a weak pull up if the chip is in PCI host mode. Follow PCI specifications recommendation.
6. These are On Die Termination pins, used to control DDR2 memories internal termination resistance.
7. This pin must always be tied to GND.
8. This pin must always be left not connected.
9. This pin must always be tied to GV_{DD}.
10. Refers to *MPC8360E PowerQUICC II™ Pro Integrated Communications Processor Reference Manual* section on “RGMII Pins” for information about the two UCC2 Ethernet interface options.
11. It is recommended that MDIC0 be tied to GND using an 18.2 Ω resistor and MDIC1 be tied to DDR power using an 18.2 Ω resistor for DDR2.

22.1 System PLL Configuration

The system PLL is controlled by the RCWL[SPMF] and RCWL[SVCOD] parameters. Table 68 shows the multiplication factor encodings for the system PLL.

Table 68. System PLL Multiplication Factors

RCWL[SPMF]	System PLL Multiplication Factor
0000	× 16
0001	Reserved
0010	× 2
0011	× 3
0100	× 4
0101	× 5
0110	× 6
0111	× 7
1000	× 8
1001	× 9
1010	× 10
1011	× 11
1100	× 12
1101	× 13
1110	× 14
1111	× 15

The RCWL[SVCOD] denotes the system PLL VCO internal frequency as shown in Table 69.

Table 69. System PLL VCO Divider

RCWL[SVCOD]	VCO Divider
00	4
01	8
10	2
11	Reserved

NOTE

The VCO divider must be set properly so that the system VCO frequency is in the range of 600–1400 MHz.

Table 72. QUICC Engine Block PLL Multiplication Factors (continued)

RCWL[CEPMF]	RCWL[CEPDF]	QUICC Engine PLL Multiplication Factor = RCWL[CEPMF]/ (1 + RCWL[CEPDF])
00101	0	× 5
00110	0	× 6
00111	0	× 7
01000	0	× 8
01001	0	× 9
01010	0	× 10
01011	0	× 11
01100	0	× 12
01101	0	× 13
01110	0	× 14
01111	0	× 15
10000	0	× 16
10001	0	× 17
10010	0	× 18
10011	0	× 19
10100	0	× 20
10101	0	× 21
10110	0	× 22
10111	0	× 23
11000	0	× 24
11001	0	× 25
11010	0	× 26
11011	0	× 27
11100	0	× 28
11101	0	× 29
11110	0	× 30
11111	0	× 31
00011	1	× 1.5
00101	1	× 2.5
00111	1	× 3.5
01001	1	× 4.5

23.2.3 Experimental Determination of Junction Temperature

To determine the junction temperature of the device in the application after prototypes are available, the Thermal Characterization Parameter (Ψ_{JT}) can be used to determine the junction temperature with a measurement of the temperature at the top center of the package case using the following equation:

$$T_J = T_T + (\Psi_{JT} \times P_D)$$

where:

T_J = junction temperature (°C)

T_T = thermocouple temperature on top of package (°C)

Ψ_{JT} = junction-to-ambient thermal resistance (°C/W)

P_D = power dissipation in the package (W)

The thermal characterization parameter is measured per JESD51-2 specification using a 40 gauge type T thermocouple epoxied to the top center of the package case. The thermocouple should be positioned so that the thermocouple junction rests on the package. A small amount of epoxy is placed over the thermocouple junction and over about 1 mm of wire extending from the junction. The thermocouple wire is placed flat against the package case to avoid measurement errors caused by cooling effects of the thermocouple wire.

23.2.4 Heat Sinks and Junction-to-Ambient Thermal Resistance

In some application environments, a heat sink will be required to provide the necessary thermal management of the device. When a heat sink is used, the thermal resistance is expressed as the sum of a junction to case thermal resistance and a case to ambient thermal resistance:

$$R_{\theta JA} = R_{\theta JC} + R_{\theta CA}$$

where:

$R_{\theta JA}$ = junction-to-ambient thermal resistance (°C/W)

$R_{\theta JC}$ = junction-to-case thermal resistance (°C/W)

$R_{\theta CA}$ = case-to-ambient thermal resistance (°C/W)

$R_{\theta JC}$ is device related and cannot be influenced by the user. The user controls the thermal environment to change the case-to-ambient thermal resistance, $R_{\theta CA}$. For instance, the user can change the size of the heat sink, the airflow around the device, the interface material, the mounting arrangement on printed-circuit board, or change the thermal dissipation on the printed-circuit board surrounding the device.

To illustrate the thermal performance of the devices with heat sinks, the thermal performance has been simulated with a few commercially available heat sinks. The heat sink choice is determined by the application environment (temperature, airflow, adjacent component power dissipation) and the physical space available. Because there is not a standard application environment, a standard heat sink is not required.

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Document Number: MPC8358EEC
Rev. 3
01/2011